





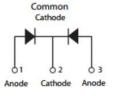
## SDURF1060CT(CTR) ULTRAFAST RECTIFIER

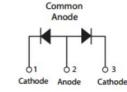


## **Applications**

- Antiparallel diode for high frequency switching devices
- · Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**





SDURF1060CT

SDURF1060CTR

#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Maximum Ratings:**

Characteristics	Symbol	Condition Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{R} \end{array}$	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	5(Per Leg) 10(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	60	A

#### **Electrical Characteristics:**

Characteristics	Symbol	ool Condition		Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@5A, Pulse, T <sub>J</sub> = 25°C	1.39	1.55	V
	V <sub>F2</sub>	@5A, Pulse, T <sub>J</sub> = 125°C	1.36	1.45	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ , $T_J = 25^{\circ}C$	0.08	5	μA
	I <sub>R2</sub>	$@V_R = rated V_R$ , $T_J = 125$ °C	63	500	μA
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	42	50	ns
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>		55	-	ns
Reverse Recovery Charge(Per Leg)	Q <sub>rr</sub>	$I_F = 5A$ , diF/dt = -200A/ $\mu$ s $V_R = 400V$ , $T_J = 25^{\circ}$ C	160	-	nC
Reverse Recovery Current(Per Leg)	I <sub>RRM</sub>	- VR - 400V, 13 - 23 C	5.8	-	Α
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>		88	-	ns
Reverse Recovery Charge(Per Leg)	Q <sub>rr</sub>	$I_F = 5A$ , diF/dt = -200A/ $\mu$ s $V_R = 400V$ , $T_J = 125$ °C	299	-	nC
Reverse Recovery Current(Per Leg)	I <sub>RRM</sub>	VR - 400V, 13 - 120 O		-	Α

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# Technical Data Data Sheet N0227, Rev.B \* Pulse width < 300 µs, duty cycle < 2%

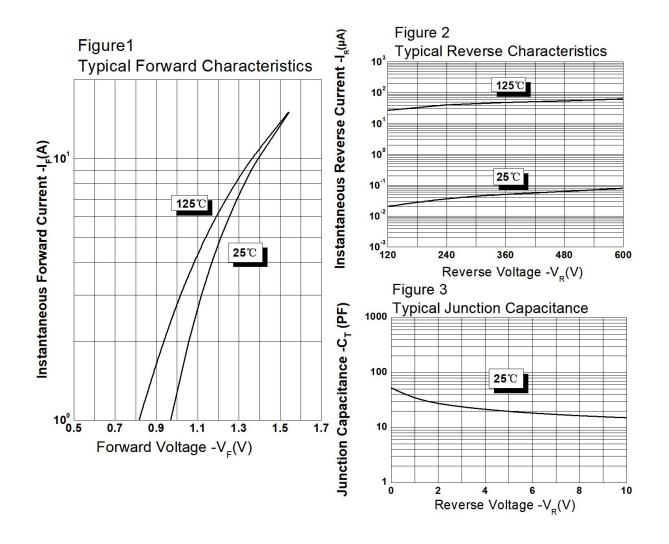




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

## **Ratings and Characteristics Curves**



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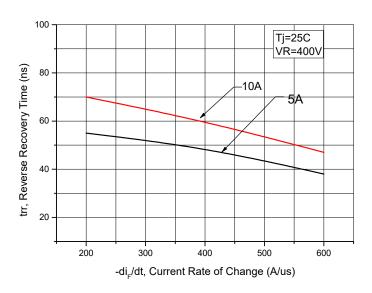


Figure 4. Reverse Recovery Time vs. Current Rate of Change

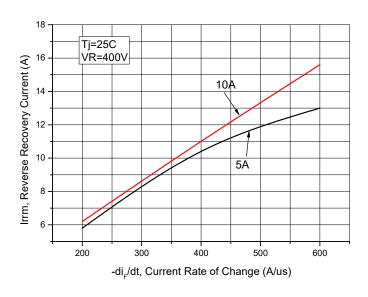


Figure 5. Reverse Recovery Current vs.

Current Rate of Change

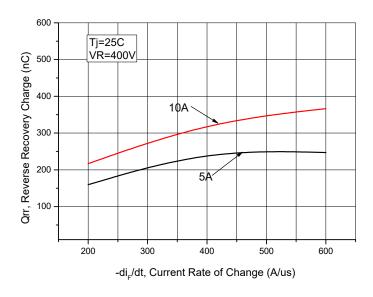


Figure 6. Reverse Recovery Charge vs. Current Rate of Change

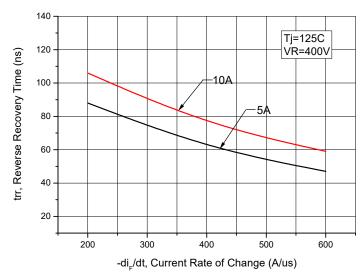


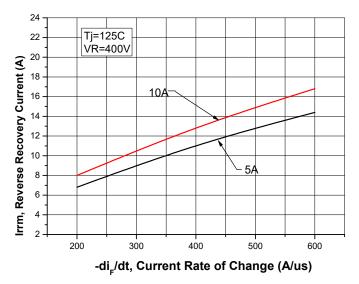
Figure 7. Reverse Recovery Time vs. Current Rate of Change

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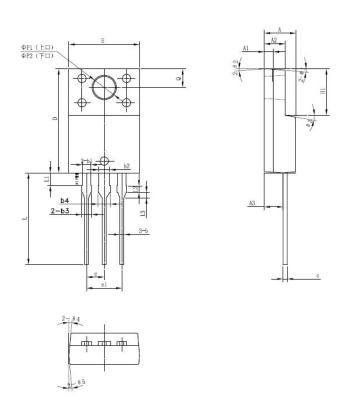


700 Tj=125C 650 VR=400V 600 Qrr, Reverse Recovery Charge (nC) 550 500 450 400 350 300 -5A 250 200 150 100 200 400 600 -di<sub>-</sub>/dt, Current Rate of Change (A/us)

Figure 8. Reverse Recovery Current vs. Current Rate of Change

Figure 9. Reverse Recovery Charge vs. Current Rate of Change

#### **Mechanical Dimensions ITO-220AB**



SYMBOL	Millimeters				
STIVIBUL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ФР1( ├ □ )	3.30	3.50	3.70		
<b>ΦP2</b> (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

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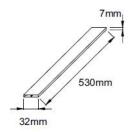








#### **Tube Specification**

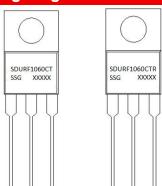


#### **Ordering Information**

Device	Package	Shipping
SDURF1060CT(CTR)	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Marking Diagram**



Where XXXXX is YYWWL

 SDUR
 = Device Type

 F
 = Package type

 10
 = Forward Current (10A)

 60
 = Reverse Voltage (600V)

 CT(CTR)
 = Configuration

 SSG
 = SSG

Cautions: Molding resin

Epoxy resin UL:94V-0

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